

STM32Lxxx Internal Flash Memory Instructions Manual

Yokogawa Digital Computer Corporation

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1 Introduction

This is a brief manual for writing to Serial flash memory.

For details of ICE operating instructions, see the microVIEW-PLUS User's Manual (Common Edition) and microVIEW-PLUS User's Manual (MPU-Specific Edition).

2 Supported SLX(ZX) Versions

Device Model	Supported Versions	
	SLX600	ZX600
STM32L100	2.51 or later	--
STM32L151	2.51 or later	--
STM32L152	2.51 or later	--
STM32L162	2.51 or later	--

3 Advance Preparation

3.1 MPU-specific Debug Control Register

In some cases, Cortex-M series core has a debug control register outside of the core. In this case, start debugging after setting the debug specific control register.

(MPU MPU-Specific Setting Synchronous memory operation)

Without settings, you may not be able to perform debug operation successfully.

The followings are setting examples.

*** Modify the settings as required.**

*** For details, see technical reference manuals for each MPU.**

Settings

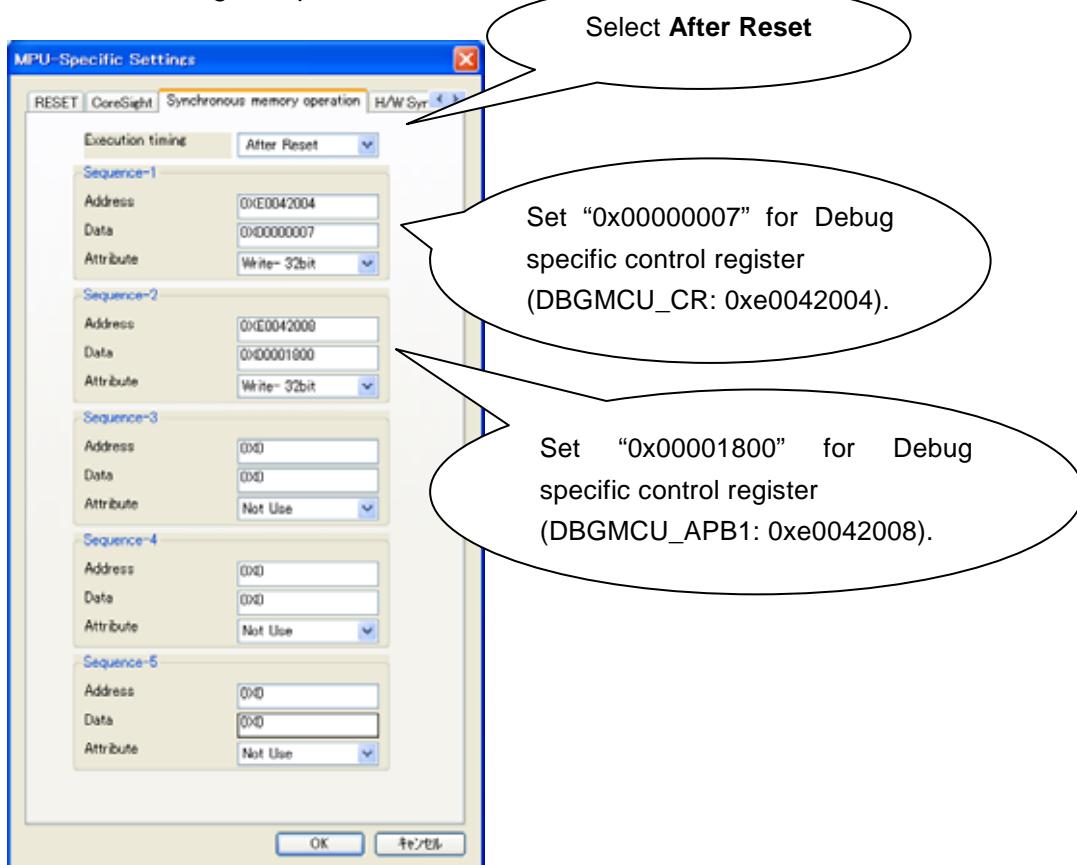
DBG_IWDG_STOP=1: Debug independent watchdog stopped when core is halted.

DBG_WWDG_STOP=1: Debug Window Watchdog stopped when Core is halted.

DBG_STANDBY=1: Debug Standby mode.

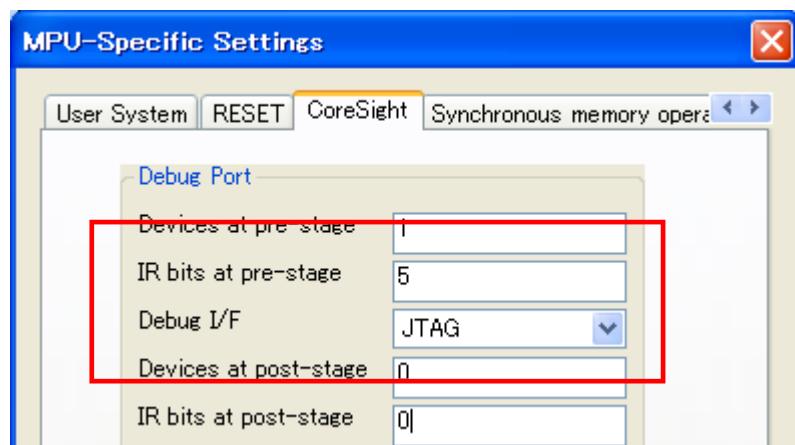
DBG_STOP=1: Debug Stop mode.

DBG_SLEEP=1: Debug Sleep mode.



3.2 Changing I/F to connect

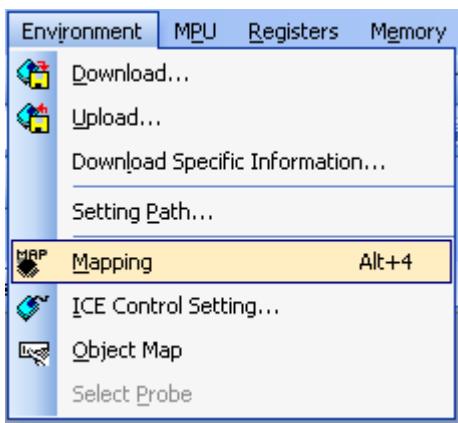
In case the debugger operation in SWD is unstable, switch it to JTAG I/F. Set the number of bypass TAP at pre-stage and the number of IR register bit at pre-stage then.



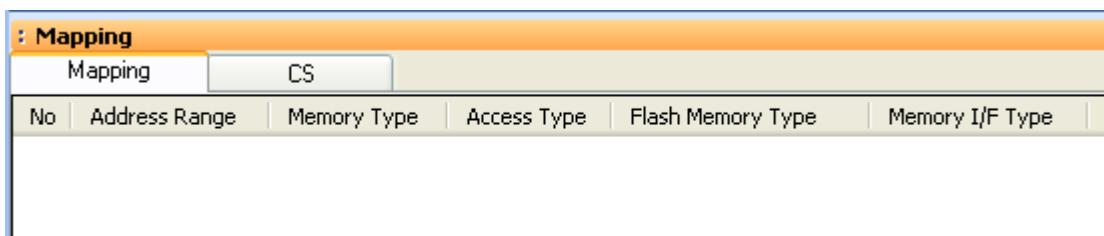
4 Setting the Memory Mapping

4.1 Setting up Flash Memory Mapping

Open the memory mapping window by clicking **Environments – Mapping**.

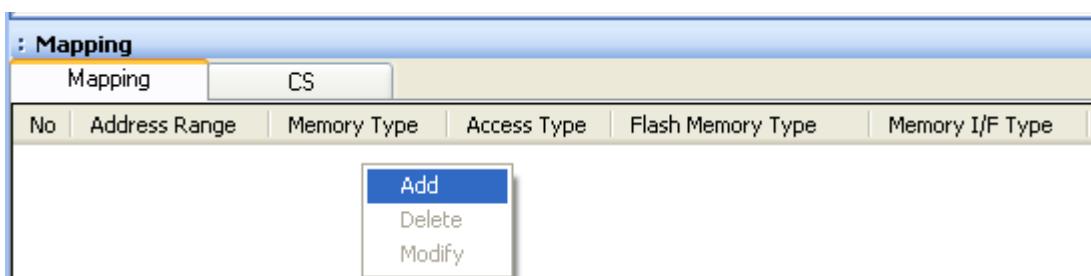


Memory map window as below is opened.

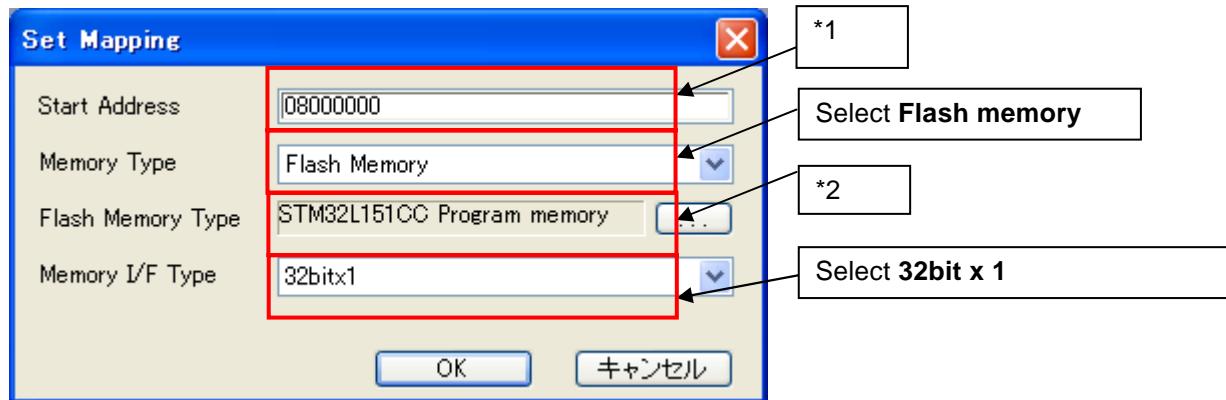


Set the mapping.

Right-click on the memory mapping window, and then select **Add**.



Configure the setting as the example below.



*1: Set the address in accordance with a mapping block.

*2: Select the flash memory definition file (.frd) in accordance with the mapping block.

The following table describes about the mapping blocks, starting addresses, and frd files.

- **Setup example for when using STM32L151CC**

Mapping block	*1 Start address	*2 Flash Memory Type
Program memory	0x08000000	STM32L151CC_Program.frd
Data Memory / EEPROM	0x08080000	STM32L151CC_Data.frd
Option byte block	0x1FF80000	STM32L151CC_OptionBytes.frd

5 Erase the Flash Memory

For details, see the microVIEW-PLUS User's Manual (MPU-Specific Edition).

Details of memory mapping settings are described on this manual. Please refer to the microVIEW-PLUS User's Manual (MPU-Specific Edition) for other contents.

6 Download to Flash Memory

For details, see the microVIEW-PLUS User's Manual (MPU-Specific Edition).

Details of memory mapping settings are described on this manual. Please refer to the microVIEW-PLUS User's Manual (MPU-Specific Edition) for other contents.

6.1 Downloadable Area

Flash memory of STM32L1xx series is sectioned as the following table.

You can program the area marked "Yes".

Block	Item	Start address	Size	Supported
Program memory		0x08000000	128KB to 384KB	Yes
Data memory/ EEPROM	DATA	0x08080000	4KB to 12KB	Yes
Information block	System memory	0x1FF00000	4KB to 8KB	No
	Option bytes block	0x1FF80000	32B to 64B	Yes

Note:

- (1) System memory area of information block cannot be overwritten due to the specification of MPU.

6.2 Downloading the readout protection (RDP) area

Data programming to an area which controls readout protection (RDP) in an option bytes block of information block is not download data. The data is always being protected at level 0.

Data actually programmed into that area is as follows.

Write address	Setting value
0x1ff80000	0xFF5500AA

Depending on the specification of chip, mass erase may be executed if you download data into RDP area when readout protection is at level 1(memory read protection enabled) condition. As a result, program area, data EEPROM area and option byte area are all erased.

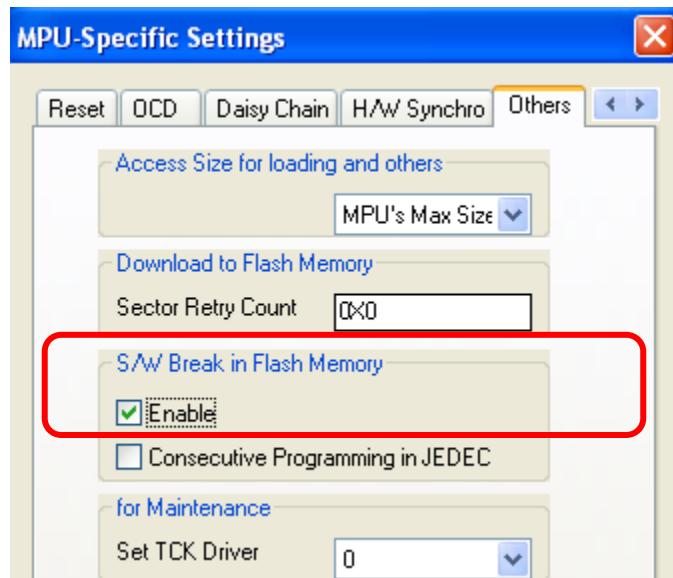
7 Software Break in Flash Memory

For details, see the microVIEW-PLUS User's Manual (MPU-Specific Edition).

Details of memory mapping settings are described on this manual. Please refer to the microVIEW-PLUS User's Manual (MPU-Specific Edition) for other contents.

You are not allowed to set up software break for flash memory in the initial state. In case you try to set up software break for flash memory in the disabled status, it results in "ICE Error No. 8c4: Set Software Break Verify Error".

To enable software break setting for flash memory, select the **Enable** checkbox of S/W Break in Flash Memory on the Others tab of the MPU-Specific Settings dialog box.



8 Notes & Points

8.1 Memory write protection

Depending on the specification of chip, the system will be reset when releasing the protection. Therefore, you cannot program the flash (*) while setting the memory write protection which uses option byte area.

Please release the memory write protection before programming the flash.

*: Programming which is accompanied by downloading, erasing and software break setting of the on-chip flash memory.